

USB Charging Port Controller with Current Limit Switch, Supporting CDP, DCP, and QC3.0 Modes

DESCRIPTION

The MP5030C integrates a USB current-limit switch and charging port identification circuit. The MP5030C achieves 3A of continuous output current over a wide input supply range.

The output of the USB switch is current-limit programmable. The MP5030C supports dedicated charging port (DCP) and charging downstream port (CDP) schemes for battery charging specification (BC1.2), divider mode, 1.2V/1.2V mode, and quick-charge specification (QC 2.0/3.0) without the need for external user interaction.

The MP5030C provides linear line drop compensation for 5V outputs.

Full protection features include hiccup current limiting, input over-voltage protection (OVP), and thermal shutdown.

The MP5030C requires a minimal number of readily available, standard, external components to complete the USB switch and charging mode auto-detection solution. The MP5030C is available in a QFN-10 (1.5mmx2mm) package.

FEATURES

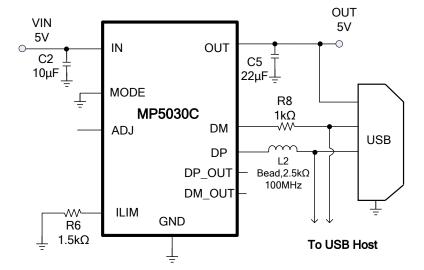
- Up to 14V Operating Input Voltage Range
- Support DCP Schemes for BC 1.2 without QC Mode, Divider Mode, and 1.2V/1.2V Mode
- Supports QC 3.0 Mode
- Support CDP Mode for USB 2.0 Data
- Line Drop Compensation for 5V Output
- Programmable High-Accuracy Current Limit
- 32mΩ Low R_{DS(ON)} Power MOSFET
- Input Over-Voltage Shutdown Protection
- Compatible with Buck, Boost, AC/DC Converters
- Available in a QFN-10 (1.5mmx2mm) Package

APPLICATIONS

- USB Charging Downstream Port (CDP)
- USB Dedicated Charging Ports (DCP)

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TYPICAL APPLICATION



CDP Mode Set-Up for USB2.0 Application



ORDERING INFORMATION

Part Number*	Package	Top Marking
MP5030CGQH	QFN-10 (1.5mmx2mm)	See Below

^{*} For Tape & Reel, add suffix -Z (e.g. MP5030CGQH-Z)

TOP MARKING

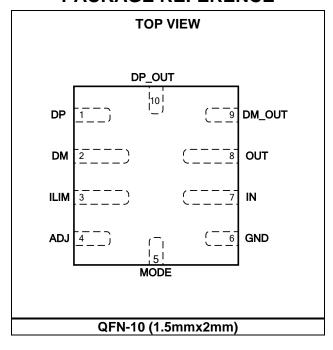
GB

LL

GB: Product code of MP5030CGQH

LL: Lot number

PACKAGE REFERENCE





ABSOLUTE MAXIMUM RATINGS (1)
Supply voltage (V _{IN})0.3V to +16V
Output voltage (V _{IN})0.3V to +16V
All other pins0.3V to +6V
Junction temperature150°C
Lead temperature260°C
Continuous power dissipation $(T_A = +25^{\circ}C)^{(2)}$
2.23W
Recommended Operating Conditions (3)
Supply voltage (V _{IN})Up to 14V (4)
Output voltage (V _{OUT})follow with V _{IN}
Output current (I _{OUT})up to 3A
Operating junction temp. (T _J)40°C to +125°C

Thermal Resistance	$oldsymbol{ heta}_{JA}$	$\boldsymbol{\theta}$ JC	
QFN-10 (1.5mmx2mm)			
EV5030C-QH-00C	56	18	°C/W
JESD51-7 ⁽⁵⁾	130	25	°C/W

NOTES:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature T_J (MAX), the junction-to-ambient thermal resistance θ_{JA} , and the ambient temperature T_A . The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D (MAX) = $(T_J$ (MAX)- T_A)/ θ_{JA} . Exceeding the maximum allowable power dissipation produces an excessive die temperature, causing the regulator to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage. Measured on EV5030C-QH-00A, 2-layer PCB, 4.4cmx2.9cm, 2Oz copper.
- The device is not guaranteed to function outside of its operating conditions.
- 4) For lower V_{IN} applications, refer to the Operation section on page 12.
- 5) Measured on JESD51-7, 4-layer PCB.



ELECTRICAL CHARACTERISTICS

 $V_{IN} = 5V$, $T_J = -40$ °C to 125°C (6), Typical value is tested at $T_J = +25$ °C, unless otherwise noted.

Parameter	Symbol	Condition	Min	Тур	Max	Units
V _{IN} under-voltage lockout rising threshold	VIN_UVLO1	ADJ starts to work	2.7	3.0	3.3	V
UVLO hysteresis	V _{UVLOHYS1}			880		mV
Second V _{IN} under-voltage lockout rising threshold	VIN_UVLO2	Power MOSFET turn-on	3.7	3.9	4.1	V
Second UVLO hysteresis	Vuvlohys2			500		mV
Start-up delay	T _{Delay}	From UVLO rising to Vout = 100mV	4	5	6	ms
Supply current	ΙQ	V _{IN} = 5V, no load		250	320	μA
USB Power MOSFET						
On resistance	Rdson	V _{IN} = 5V		32	50	mΩ
Input discharge resistance	RDIS	Turn-on during V _{IN} OVP or H to L voltage change period		72		Ω
Soft-start time	Tss	V _{IN} = 5V, no load, 10% to 90%		290		μs
Current Limit Set				•	•	•
USB current limit	I _{LIMIT}	$R_{ILIM} = 1.5k\Omega$, V_{OUT} drops 10%	3.13	3.35	3.57	Α
Output Voltage Control				•	•	•
Defection	V _{IN_Def1}	I _{OUT} = 0A, T _J = +25°C	-1%	5	+1%	V
Default V _{IN}	V _{IN_Def2}	$T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	-2%	5	+2%	
9V _{IN} voltage	V _{IN_9}	T _J = +25°C	-2%	9	+2%	V
12V _{IN} voltage	V _{IN_12}	T _J = +25°C	-2%	12	+2%	V
V _{ADJ} sink current capability	I _{sink}	$V_{FB} = 800 \text{mV}$	500			μΑ
Line drop compensation	V _{IN_5_C}	I _{OUT} = 2.4A, only 5V _{IN} active		220	350	mV
Protection						
		V _{IN} rising edge, V _{IN} = 5V	110	115	120	
V _{IN} OVP threshold	V _{OV_TH}	V _{IN} rising edge, V _{IN} = 9V	110	115	120	%
		V _{IN} rising edge, V _{IN} = 12V	110	115	120	
V _{IN} OVP recovery	V _{OV_Recovery}	Reset mode to 5V default	5.25	5.4	5.55	V
OVP deglitch time (7)	T _{OVP_DE}			10		μs
OCP on time of hiccup	T _{HIC_ON}			2		ms
OCP off time of hiccup	THIC_OFF			2		S
Shutdown temperature (7)	T _{STD}			160		°C
Hysteresis (7)	T _{HYS}			35		°C
MODE Selection						
		MODE = high, DCP mode with QC function	2.1			
MODE voltage	VMODE	MODE = float, DCP mode without QC function	0.9		1.9	V
		MODE = low, CDP mode			0.5	



ELECTRICAL CHARACTERISTICS (continued)

 $V_{IN} = 5V$, $T_J = -40$ °C to 125°C (6), Typical value is tested at $T_J = +25$ °C, unless otherwise noted.

Parameter	Symbol	Condition	Min	Тур	Max	Units
BC 1.2 DCP Mode		•	<u>l</u>	<u> </u>		
DP/DM short resistance	RDP/DM_Short	$V_{DP} = 0.8V$, $I_{DM} = 1$ mA, $T_{J} = +25$ °C			50	Ω
1.2V/1.2V Mode			•			
DP/DM output voltage	$V_{\text{DP/DM_1.2V}}$		1.1	1.2	1.3	V
DP/DM output impedance	R _{DP/DM_1.2V}			300		kΩ
Divider Mode						
DP/DM output voltage	V _{DP/DM}	V _{IN} = V _{OUT} = 5V	2.5	2.7	2.85	V
DP/DM output impendence	R _{DP/DM}		18	22	28	kΩ
Quick Charge 3.0 Mode			•			
Data detect voltage	V _{DAT_REF}		0.25	0.3	0.4	V
Output voltage select ref	V _{SEL_REF}		1.8	2	2.2	V
DP output impendence	R _{DP_QC}		250	350	450	kΩ
DM output impendence	R _{DM_QC}		15	20	25	kΩ
DM low glitch time	T _{Glitch_DM}			10		ms
DP high glitch time	T _{Glitch_DP}		1000		1500	ms
Output voltage change glitch time	T _{Glitch_V_Change}		20	40	60	ms
V _{BUS} voltage step	V _{step}		150	200	250	mV
CDP Mode						
DM CDP output voltage	V_{DM_SRC}	VDP = 0.6V	0.5	0.6	0.7	V
DP rising lower window threshold for V _{DM_SRC} activation	V _{DAT_} RE		0.25	0.3	0.4	V
DP rising lower window threshold hysteresis for V _{DM_SRC} activation	V _{DAT_RE_HYS}			50		mV
DP rising upper window threshold for V _{DM_SRC} deactivation	V _{LGC_SRC}			1.9	2	V
DP rising upper window threshold hysteresis for V _{DM_SRC} de-activation	VLGC_SRC_HYS			200		mV
V _{DM_SRC} on/off deglitch time	$V_{\text{DM_SRC_Deglitch}}$		3.8	4.8	5.8	ms
RDP_Down, RDM_Down	R _{DP/DM_Down}		14.25	19.5	24.8	kΩ
DP/DM switch on resistance	Ron_dp/dm			2.5		Ω
DP to DP_OUT SW on cap	C_DP	Same for DM switch		5.3		pF
3dB bandwidth of analog data SW ⁽⁷⁾	F _{BW}		500			MHz

NOTES:

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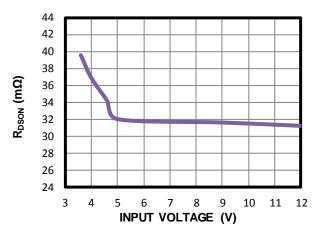
⁶⁾ Guaranteed by over-temperature correlation, not tested in production.7) Guaranteed by engineering sample characterization.



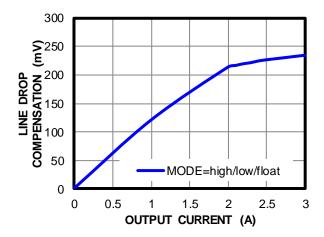
TYPICAL CHARACTERISTICS

 $V_{IN} = 5V$, $V_{OUT} = 5V$, $R_{ILIM} = 1.5k\Omega$, $T_A = 25$ °C, unless otherwise noted.

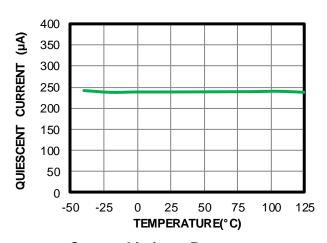
R_{DS(ON)} vs. Input Voltage



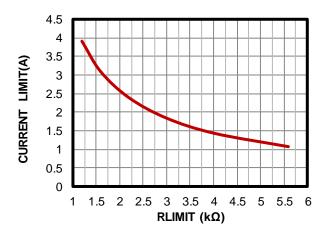
Line Drop Compensation



Quiescent Current vs. Temperature



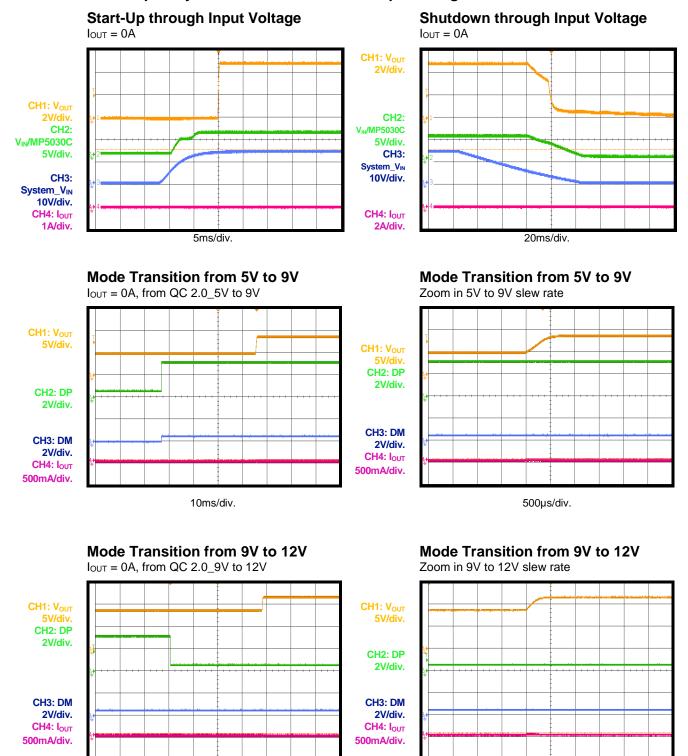
Current Limit vs. RLIMIT





TYPICAL PERFORMANCE CHARACTERISTICS (continued)

 V_{IN} = 5V, V_{OUT} = 5V, R_{ILIM} = 1.5k Ω , T_{A} = 25°C, unless otherwise noted. Connect the MP5030C input to the MP2499A output. System_VIN is the MP2499A input voltage.



10ms/div.

500µs/div.

CH1: V_{OUT}

5V/div.

CH2: DP

CH3: DM

CH4: I_{OUT} 500mA/div.

CH1: V_{OUT}

V_{IN}/MP5030C

5V/div.

5V/div.

CH4: I_{OUT}

CH1: V_{OUT}

V_{IN}/MP5030C 5V/div.

CH4: I_{OUT}

2A/div.

5V/div.

CH2:

2A/div.

CH2:

2V/div.

2V/div.

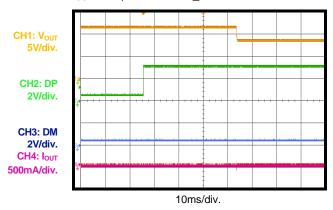


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

 $V_{IN} = 5V$, $V_{OUT} = 5V$, $R_{ILIM} = 1.5k\Omega$, $T_A = 25$ °C, unless otherwise noted. Connect the MP5030C input to the MP2499A output. System VIN is the MP2499A input voltage.

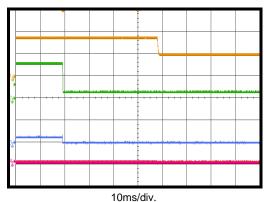


I_{OUT} = 0A, from QC 2.0 12V to 9V



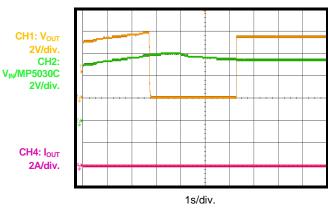
Mode Transition from 9V to 5V

 $I_{OUT} = 0A$, from QC 2.0 9V to 5V



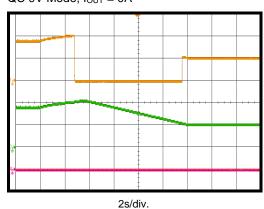
Input Over-Voltage Protection

QC 5V Mode, I_{OUT} = 0A



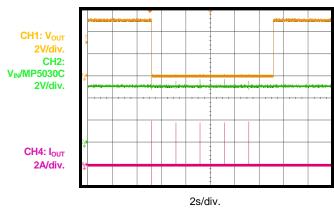
Input Over-Voltage Protection

QC 9V Mode, $I_{OUT} = 0\overline{A}$



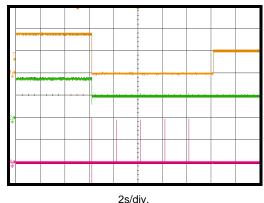
Short-Circuit Protection Entry and Recovery

 $V_{IN} = 5V$. $I_{OUT} = 0A$



Short-Circuit Protection Entry and Recovery

 $V_{IN} = 9V$. $I_{OUT} = 0A$



5V/div.

CH2: DM

CH3: DP

1V/div.

1A/div.

CH4: **I**CHARGE

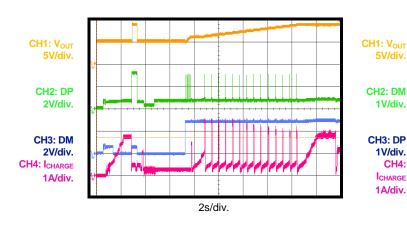
1V/div.



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

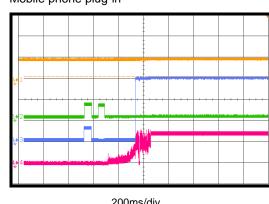
 $V_{IN} = 5V$, $V_{OUT} = 5V$, $R_{ILIM} = 1.5k\Omega$, $T_A = 25$ °C, unless otherwise noted. Connect the MP5030C input to the MP2499A output. System VIN is the MP2499A input voltage.

QC 3.0 Device Charging Test



CDP Mode Detection

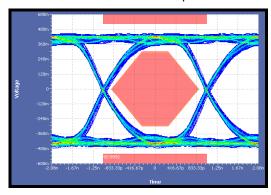
Mobile phone plug-in



200ms/div.

Eye Pattern Test

Recommended CDP mode set-up





PIN FUNCTIONS

Package Pin #	Name	Description
1	DP	D+ data line to USB connector. DP is the input/output used for handshaking with portable devices.
2	DM	D- data line to USB connector. DM is the input/output used for handshaking with portable devices.
3	ILIM	Set the current limit level. Place a resistor between ILIM and GND to achieve a high-accuracy current limit.
4	ADJ	Output voltage adjustment. ADJ sinks a current from the upstream DC/DC converter's FB pin to ground to regulate the DC/DC converter's output voltage. ADJ also supports line drop compensation.
5	MODE	USB mode control. Float MODE to operate the USB in DCP mode without the QC function. Pull MODE high to operate the USB in DCP mode with the QC function. Pull MODE low to operate the USB in CDP mode. MODE has a $1M\Omega$ pull-up resistor to an internal +1.2V source.
6	GND	Ground.
7	IN	Supply voltage.
8	OUT	Output of the USB current limit switch.
9	DM_OUT	D- data line to the USB host controller.
10	DP_OUT	D+ data line to the USB host controller.



BLOCK DIAGRAM

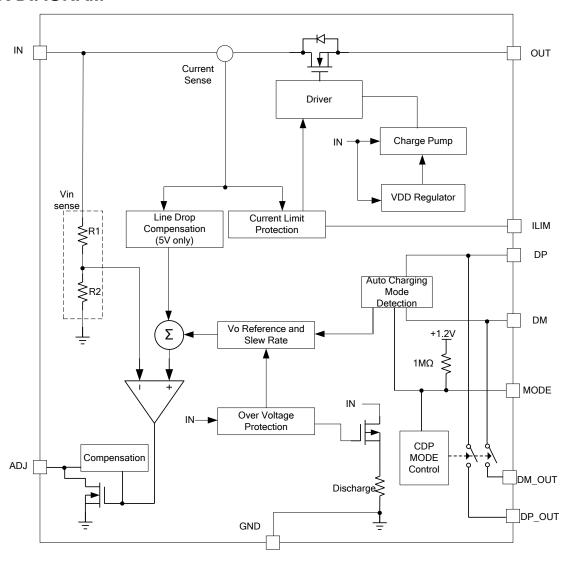


Figure 1: Functional Block Diagram



OPERATION

The MP5030C integrates a USB current-limit switch and charging port identification circuit. The MP5030C achieves 3A of continuous output current over a wide input supply range.

The output of the USB switch is current-limited with an adjustable current-limit threshold. The MP5030C supports the quick-charge specification (QC 3.0) and is backwards-compatible with QC 2.0. The MP5030C also supports DCP/CDP schemes for battery charging specification (BC1.2), divider mode, and 1.2V/1.2V mode without the need for external user interaction.

The MP5030C provides line drop compensation for a 5V output. Fault condition protection includes hiccup current limiting, input overvoltage protection (OVP), and thermal shutdown.

Operation Supply Voltage

The MP5030C has a two-stage input voltage threshold. The first threshold is around 3V, and the second threshold is the under-voltage lockout (UVLO) of the power MOSFET. When $V_{\rm IN}$ is higher than the first threshold, the MP5030C's ADJ block starts working and sinks a current to adjust the upstream regulator's output to an accurate 5V. Afterward, the MP5030C enters a fully working state.

Under-Voltage Lockout (UVLO)

UVLO protects the chip from operating at an insufficient supply voltage. The MP5030C's second UVLO comparator monitors the input voltage. Once the input voltage is higher than the second UVLO threshold, the power MOSFET starts to turn on with a controlled slew rate after a fixed delay.

Internal Soft Start (SS)

The internal soft-start prevents the output voltage from inrush current and overshooting during start-up.

MODE Selection

The MP5030C supports DCP and CDP modes through MODE control. Pull MODE high to operate the USB in DCP mode with the QC function. Float MODE to operate the USB in DCP mode without the QC function. Pull MODE low to operate the USB in CDP mode.

In DCP mode, the MP5030C can provide power for USB devices with protocol auto-detection. It supports the following charging schemes:

- USB battery charging specification BC1.2/Chinese Telecommunications Industry
- Standard YD/T 1591-2009
- Divider mode
- 1.2V/1.2V mode
- Quick-charge mode 2.0
- Quick-charge mode 3.0 (3.6 12V)

For better data transmission performance in CDP mode, use the MP5030C in USB CDP mode for handshaking. Bypass DP to DP_OUT. DM to DM_OUT switches internally (see Figure 2).

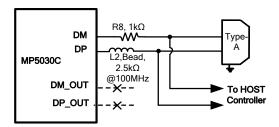


Figure 2: CDP Mode Set-Up

In CDP mode, the bus voltage (V_{BUS}) is always around 5V with current limit and line drop compensation (see Table 1).

Table 1: MODE Selection

MODE Status	Supported Charge Mode
Logic high	DCP mode, divider mode, QC2.0, QC3.0 mode, 1.2V/1.2V mode
Float	DCP mode without QC function, divider mode, 1.2V/1.2V mode
Logic low	CDP mode, 5V _{OUT} with line drop compensation

Connect DP and DM with a 150Ω resistor for DCP without QC mode.

Line Drop Compensation

The MP5030C can compensate for an output voltage drop, such as high impedance caused by a long trace, to maintain a fairly constant 5V load-side voltage. Line drop compensation is achieved through ADJ. The MP5030C increases the input voltage by 220mV at a 2.4A output current (see Figure 3).

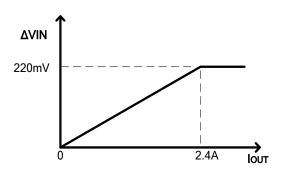


Figure 3: Line Drop Compensation

V_{ADJ} sinks a controlled current slowly. The line drop compensation amplitude increases linearly as the load current increases.

In no-load condition, if the input voltage is lower than 5V (typical), ADJ sinks a current to regulate the upstream regulator's output voltage to 5V. If the input voltage is higher than 5V (typical), the MP5030C no longer regulates the input voltage.

Input Over-Voltage and Discharge

To protect the downstream device from an over-voltage condition, the MP5030C provides an input over-voltage protection (OVP) shutdown function. Since the MP5030C supports the QC 3.0 protocol, it has a dynamic OVP threshold.

An accurate and fast comparator monitors the over-voltage condition of the input. If the input voltage rises above the threshold, the gate of the internal MOSFET is pulled low quickly, and the power MOSFET is shut down. Simultaneously, the input-to-ground discharge path is active. When the input voltage falls below 5.4V (typical), the MP5030C exits OVP mode.

The OVP shutdown function is blanked during the high-to-low voltage mode change period.

The input-to-ground discharge resistance is always active during the high-to-low voltage mode change period. The discharge path is turn-off when FB is lower than 108% times the reference voltage (V_{REF}) with 20ms of additional delay (see Figure 4).

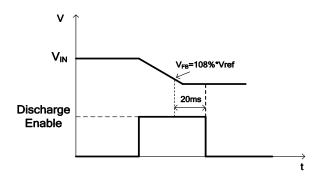


Figure 4: Input Discharge during High Voltage to Low Voltage Transition

QC mode is reset during the OVP rising edge.

Over-Current Protection (OCP)

The MP5030C provides a constant current limit. The current limit threshold is adjustable by an external resistor.

Once the device reaches its current limit threshold, the internal circuit regulates the gate voltage to hold the current in the power MOSFET constant.

The external resistor (R_{Limit}) can set the current limit threshold. If an over-current (OC) condition occurs but V_{OUT} is higher than 3.5V, the MP5030C works at a constant current (CC) limit mode without hiccup mode. If the OC is triggered and V_{OUT} is lower than 3.5V for 2ms, the MP5030C enters hiccup mode. In hiccup mode, the MP5030C turns off the power MOSFET (see Figure 5).

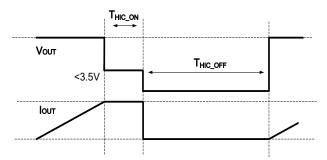


Figure 5: Over-Current Protection



Short-Circuit Protection (SCP)

If the load current increases rapidly due to a short circuit, the current may exceed the current-limit threshold greatly before the control loop can respond. If the current reaches an internal secondary current-limit level (about 6A), a fast turn-off circuit activates to turn off the power MOSFET. This limits the peak current through the switch to limit the input voltage drop. The typical fast-off response time value is 700ns. If the fast off-works, the power MOSFET remains off for 80µs. Afterward, the power MOSFET turns on again. If the part is still in a short-circuit condition, the MP5030C treats this as an over-current condition and enters hiccup mode or thermal shutdown. After the shortcircuit condition is removed, the MP5030C recovers automatically.

Thermal Shutdown

Thermal shutdown prevents the chip from operating at exceedingly high temperatures. When the silicon die temperature exceeds 160°C, the entire chip shuts down. When the temperature falls below its lower threshold (typically 135°C), the chip is enabled again.

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APPLICATION INFORMATION

Selecting the Input Capacitor

low ESR capacitors for the performance. Ceramic capacitors with X5R or dielectrics are highly recommended low ESR because of their and temperature coefficients. A 22µF ceramic capacitor is recommended for most applications. The input capacitor must also consider prestage converter stability. The input capacitor of the MP5030C is the output capacitor of the converter. Ensure that the converter is stable with an additional output capacitor.

Selecting the Output Capacitor

Use low ESR capacitors for the best performance. Ceramic capacitors with X5R or X7R dielectrics are highly recommended because of their low ESR and small temperature coefficients. A 22µF ceramic capacitor is recommended for most applications.

Selecting the ILIM Resistor

The current limit value can be set by the ILIM resistor. See the current limit vs. ILIM resistor graph on page 6. Connecting the ILIM resistor to GND can set a maximum current limit of 4.3A. The current limit threshold should be 20% higher than the maximum load current. For example, if the system's full load is 3A, set the current limit to 3.6A.

Selecting the V_{ADJ} Resistor

ADJ has an internal, controlled, current sink. Line drop compensation is achieved through ADJ. The ADJ sink current capability is $500\mu A$. It is recommended that the pre-side converter use a $k\Omega$ -level feedback resistor. The current through the high-side feedback resistor should be less than $500\mu A$. Select R1 with Equation (1):

$$R1(k\Omega) > \frac{V_{OUT}(V) - V_{FB}(V)}{0.5}$$
 (1)

There is another V_{ADJ} configuration to limit the maximum output voltage. Insert a resistor (R7) between FB and V_{ADJ} . With R7, the maximum output voltage can be limited by Equation (2):

$$V_{OUT_Max}(V) = \frac{R_1 + R_2 // R_7}{R_2 // R_7} \times V_{FB}(V)$$
 (2)

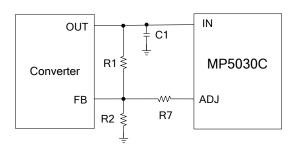


Figure 6: V_{ADJ} Set Maximum V_{OUT}

Other Considerations

The upstream DC/DC converter must have a current-limit threshold higher than the MP5030C's current limit.

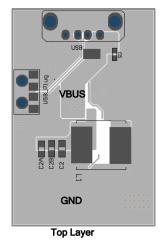
PCB Layout Guidelines (8)

Efficient PCB layout is critical for stable operation and thermal dissipation. For best results, refer to Figure 7 and follow the guidelines below.

- 1. Use short, direct, and wide traces to connect the IC's IN/OUT pins.
- 2. Add vias under the IC.
- 3. Route the OUT trace on both PCB layers.
- Place a ceramic input decoupling capacitor as close to IN and GND as possible to improve EMI performance.
- 5. Keep the V_{ADJ} trace to the pre-side converter FB pin as short as possible to prevent noise injection.

NOTE:

8) The recommended layout is based on the Typical Application Circuit in Figure 8 through Figure 10.



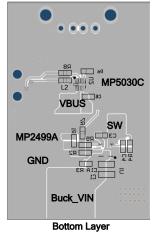


Figure 7: Recommended Layout



TYPICAL APPLICATION CIRCUITS

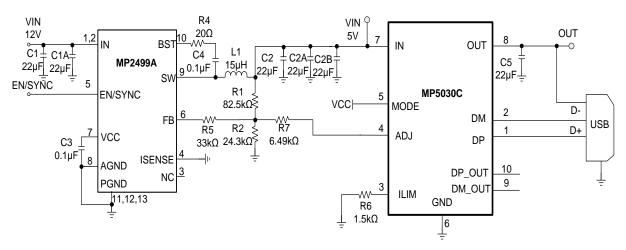


Figure 8: MP5030C + MP2499A for CLA Car Charger, DCP Mode w/ QC

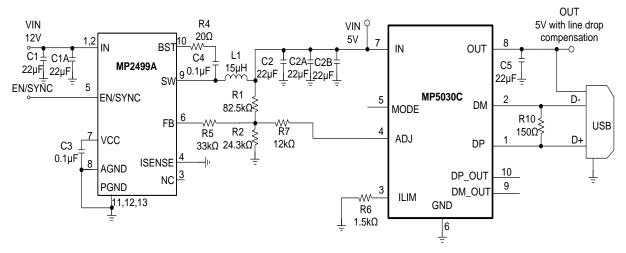


Figure 9: MP5030C + MP2499A for CLA Car Charger, DCP Mode w/o QC

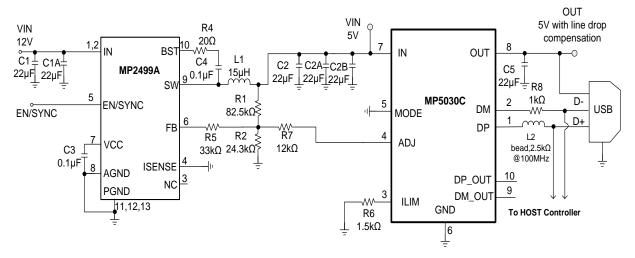
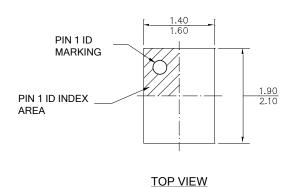


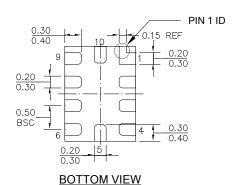
Figure 10: MP5030C + MP2499A for CDP Mode

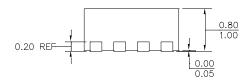


PACKAGE INFORMATION

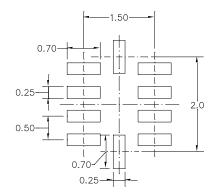
QFN-10 (1.5mmx2mm)







SIDE VIEW



RECOMMENDED LAND PATTERN

NOTE:

- 1) ALL DIMENSIONS ARE IN MILLIMETERS.
- 2) LEAD COPLANARITY SHALL BE 0.10 MILLIMETERS MAX.
- 3) JEDEC REFERENCE IS MO-220.
- 4) DRAWING IS NOT TO SCALE.

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9/28/2018